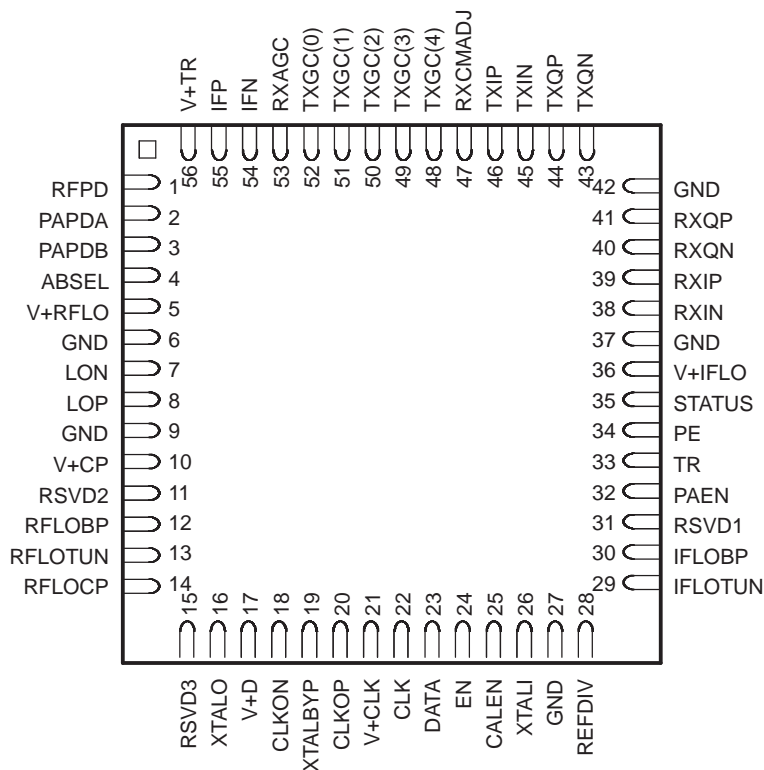


## Dual-Band IQ/IF TRANSCEIVER WITH DUAL VCO SYNTHESIZERS

### FEATURES

- Highly Integrated 802.16 d/e Radio IQ/IF Transceiver PLL ASIC
- Fully Integrated IF and RF VCOs and Synthesizers
- Super Heterodyne Architecture for Superior Performance
- Internal PLL Reference Oscillator with Clock Output for Base-Band ASICs
- Internal AGC and Power Control Function
- IQ DC Offset Calibration Function and
- Anti-Aliasing Filters Integrated
- Differential LO and IF Interface for Enhanced Spurious Immunity
- Lead Free Package
- RF LO Frequency Range:
  - 2651 – 3150 MHz
- Phase Noise 0.5 Degrees RMS Typical over Channel BW
- Reference Frequency: 40 or 44 MHz
- Single 3.3-V Power Supply
- IF = 374 MHz (Both Bands)

TBD PACKAGE  
(TOP VIEW)



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.



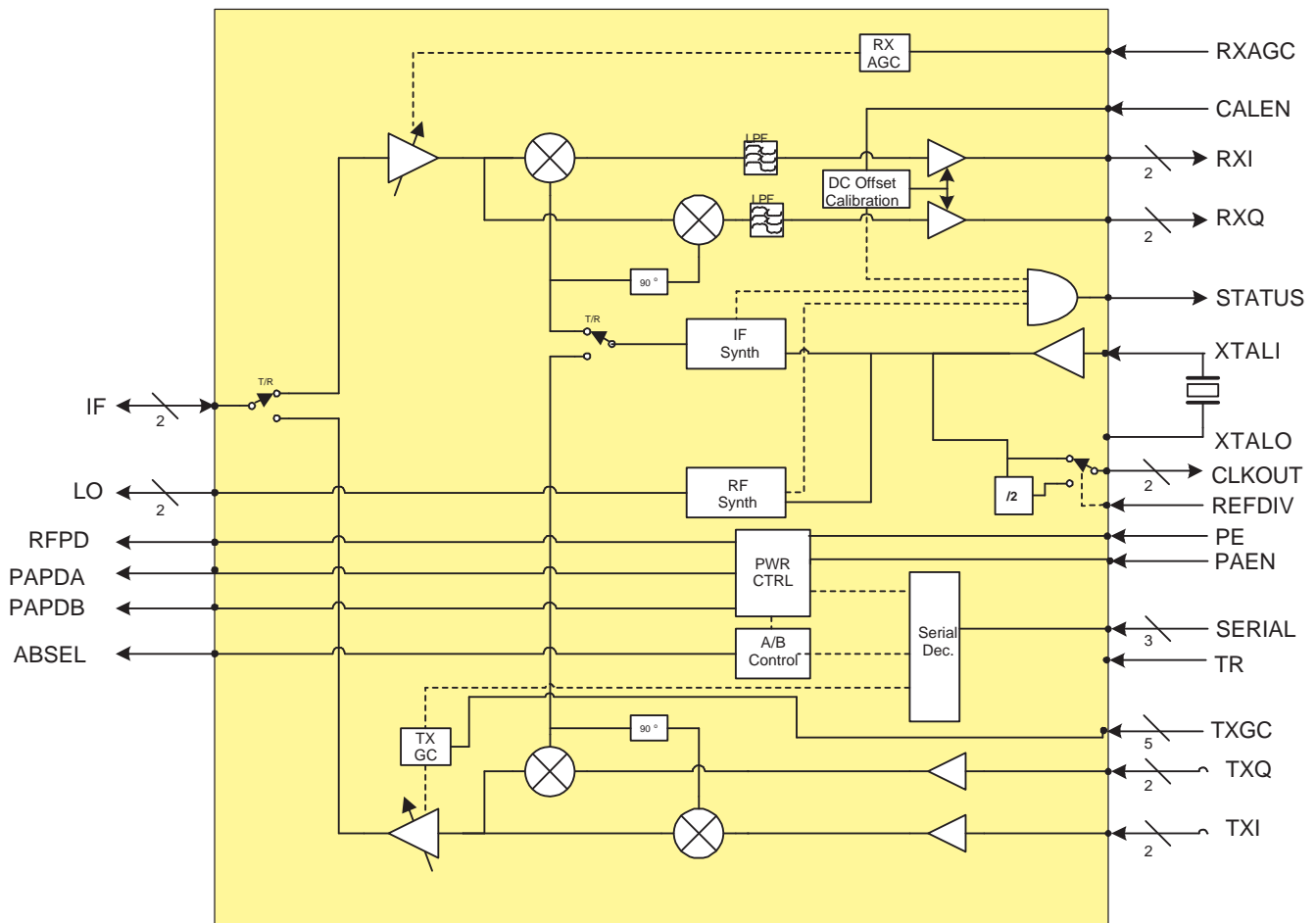
These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

## DESCRIPTION

The TRF2432 is a fully integrated IQ transceiver specifically for use in 802.16 d/e applications. The TRF2432 is designed to perform the IQ conversion at 374MHz IF as well as provide an RFLO and control logic to a TI RFFE (Radio Frequency Front End). The TRF2432 uses a common IF frequency for both bands, which eliminates the need for an additional IF filter in dual band applications. The TRF2432 has an internal IQ DC offset calibration function for the receive IQ interface. Combined with a TI integrated RFFE, the TRF2432 completes the TI WLAN two-chip radio.

The TRF2432 incorporates all of the system blocks from the modem to the RFFE except for the IF filtering and the reference crystal. The ASIC uniquely incorporates an internal PLL reference oscillator where only a crystal is needed, and also provides a clock output for base-band/MAC ASICs. TRF2432 includes two synthesizers with VCOs, IQ modulator, IQ demodulator, anti aliasing filters, IF amplifiers, receive AGC circuit, transmit power control and serial interface.

Functional Block Diagram



**DEVICE INFORMATION**
**Table 1. TERMINAL FUNCTIONS**

TERMINAL		I/O	TYPE	DESCRIPTION
NAME	NO.			
RFPD	1	O	Analog	RFFE sleep output
PAPDA	2	O	Analog	PA band A select to RFFE
PAPDB	3	O	Analog	PA band B select to RFFE
ABSEL	4	O	Analog	A or B band select to RFFE
V+RFLO	5	I	Power	+3.3V Power Supply. RF VCO bias
GND	6	I	Analog	Connect to ground per suggested layout for normal operation
LON	7	O	RF Dif.	Positive going LO output
LOP	8	O	RF Dif.	Negative going LO output
GND	9	I	Analog	Connect to ground per suggested layout for normal operation
V+CP	10	I	Power	+3.3V Power Supply. Synthesizer Charge Pumps bias
RSVD2	11	-	-	Reserved. Leave open
RFLOBP	12	O	Analog	Bypass Capacitor for LO1 (RF)
RFLOTUN	13	I	Analog	VCO Synthesizer 1 (RF) Tuning port
RFLOCP	14	O	Analog	Synthesizer 1 (RF) Charge pump output
RSVD3	15	-	-	Reserved. Leave open
XTALO	16	I/O	Analog	Negative crystal connection
V+D	17	I	Power	+3.3V Power Supply. Digital Bias
CLKON	18	O	Digital	Negative going reference clock output (40,44,20 or 22MHz)
XTALBYP	19	O	Analog	Bypass Capacitor for crystal oscillator
CLKOP	20	O	Digital	Positive going reference clock output (40,44,20 or 22MHz)
V+CLK	21	I	Power	+3.3V Power Supply. Reference Clock Bias
CLK	22	I	Digital	Clock line of 3-wire serial bus
DATA	23	I	Digital	Data line of 3-wire serial bus
EN	24	I	Digital	Load enable line of 3-wire serial bus
CALEN	25	I	Digital	A transition high in RX active mode initiates DC offset calibration. Low disables calibration circuit. Internal pull down
XTALI	26	I/O	Analog	Positive crystal connection. Also input for external XO reference
GND	27	I	Analog	Connect to ground per suggested layout for normal operation
REFDIV	28	I	Digital	Sets reference clock divider. Set HIGH to activate divide by 2. Internal pull down.
IFLOTUN	29	I	Analog	VCO Synthesizer 2 (IF) Tune port. CP2 Connected internally
IFLOBP	30	O	Analog	Bypass Capacitor for LO2 (IF)
RSVD1	31	-	-	Reserved. Leave open.
PAEN	32	I	Digital	PA enable. HIGH enables RFFE PA. Enables PAPDA or PAPDB. Internal pull down.
TR	33	I	Digital	Transmit or Receive control line. TX=HIGH, RX=LOW. Internal pull down.
PE	34	I	Digital	Power enable. HIGH is enabled. Not defined internally.
STATUS	35	O	Digital	RF, IF and REF synthesizer lock detect and calibration status.
V+IFLO	36	I	Power	+3.3V Power Supply. IF VCO bias
GND	37	I	Analog	Connect to ground per suggested layout for normal operation
RXIN	38	O	Analog	Receiver in-phase negative going output.
RXIP	39	O	Analog	Receiver in-phase positive going output.
RXQN	40	O	Analog	Receiver quadrature negative going output.
RXQP	41	O	Analog	Receiver quadrature positive going output.
GND	42	I	Analog	Connect to ground per suggested layout for normal operation
TXQN	43	I	Analog	Transmitter quadrature negative going output.

**DEVICE INFORMATION (continued)****Table 1. TERMINAL FUNCTIONS (continued)**

TERMINAL		I/O	TYPE	DESCRIPTION
NAME	NO.			
TXQP	44	I	Analog	Transmitter quadrature positive going output.
TXIN	45	I	Analog	Transmitter in-phase negative going output.
TXIP	46	I	Analog	Transmitter in-phase positive going output.
RXCMADJ	47	I	Analog	Connect resistor to ground to adjust common mode output voltage
TXGC[4]	48	I	Digital	TX Gain Control bit 4 (MSB). Logic LOW induces 16dB Atten. Internal pull down.
TXGC[3]	49	I	Digital	TX Gain Control bit 3. Logic LOW induces 8dB Atten. Internal pull down.
TXGC[2]	50	I	Digital	TX Gain Control bit 2. Logic LOW induces 4dB Atten. Internal pull down.
TXGC[1]	51	I	Digital	TX Gain Control bit 1. Logic LOW induces 2dB Atten. Internal pull down.
TXGC[0]	52	I	Digital	TX Gain Control bit 0 (LSB). Logic LOW induces 1dB Atten. Internal pull down.
RXAGC	53	I	Analog	Receiver automatic gain control pin.
IFN	54	I/O	RF Dif.	IF positive going input or output.
IFP	55	I/O	RF Dif.	IF negative going input or output.
V+TR	56	I	Power	+3.3V Power Supply. TX and RX IF amplifier bias.

**ABSOLUTE MAXIMUM RATINGS**

over operating free-air temperature range (unless otherwise noted)

	UNIT
DC supply voltage, $V_{CC}$	0 to 5.5 V
DC supply current, $I_{CC}$	600 mA
RF input power	Any port and any mode +10 dBm
Digital input voltage, $V_{ID}$	-0.3 V to $V_{CC}+0.3$ V
Analog input voltage, $V_{IA}$	0 to 3.6 V
Junction temperature, $T_{JC}$	125°C
Thermal resistance junction-to-case, $\theta_{JC}$	25°C/W
Operating temperature, $T_A$	-20°C to +85°C
Storage temperature, $T_{stg}$	-40°C to +105°C
Lead temperature	40 sec maximum +220°C

**DC CHARACTERISTICS**

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
$V_{CC}$	Supply voltage	Specification compliant	2.7	3.3	3.6	V
	Transmit Mode Supply Current	TR = High, Active mode		100	125	mA
	Receive Mode Supply Current	TR = Low, Active mode		90	110	mA
	Idle Mode Supply Current			70	85	mA
	Standby Mode Supply Current			10	15	mA
	Sleep Mode Supply Current				10	$\mu$ A
	DC current, V+RFLO	$V_{CC} = 3.3$ V, $0 < V+RFLO < V+TR + 0.6$ V	Standby	0		
			Idle	0		
			Tx	11		
			Rx	11		

**DC CHARACTERISTICS (continued)**

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
DC current, V+CP		V+TR - 0.6V < V+CP < V+TR + 0.6V	Standby	0		
			Idle	0.6		
			Tx	0.6		
			Rx	0.6		
DC current, V+D		V+TR - 0.6V < V+D < V+TR + 0.6V	Standby	8.5		
			Idle	50/30		
			Tx	50/30		
			Rx	50/30		
DC current, V+CLK		V+TR - 0.6V < V+CLK < V+TR + 0.6V	Standby	4		
			Idle	4		
			Tx	4		
			Rx	4		
DC current, V+IFLO		0 < V+IFLO < V+TR + 0.6V	Standby	0		
			Idle	0		
			Tx	8.5		
			Rx	8.5		
DC current, V+TR		3.6 V max	Standby	0.35		
			Idle	0.35		
			Tx	33/21		
			Rx	20		

**RECEIVER CHARACTERISTICS**

T<sub>A</sub> = 25°C and V<sub>CC</sub> = 3.3 V (unless otherwise noted)

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
f <sub>IF</sub>	IF input frequency			374		MHz
	Voltage gain	Gain control < 0.3 V	62	71		dB
	Analog Gain Control Range	V <sub>AGC</sub> from .3 to 2.2V	55			dB
	Gain Control Sensitivity	Monotonic.		-40	-50	dB/V
	Gain Control Linearity	From linear		±3		
	Gain settling time	Full range to within 0.5dB final gain setting		0.25		µs
	Output P <sub>-1dB</sub>		-7			dBm
	Output 3rd order intercept point			4.8		Vppd
	Noise figure	From Full Gain to 40dB gain. Not to increase more than 1dB per 1dB of gain change thereafter.		7		dB
	I/Q differential impedance	I, Q outputs (0-11MHz)			100	Ω
	Output load impedance	Single ended	2  10			kΩ  pF
	Output swing				1000	mVpd
	Input return loss	Measured into 200-Ω differential	9			dB
	Output common mode voltage	Adjustable by one resistor to ground. V <sub>com</sub> = 0.56 + 0.48 × R <sub>ADJ</sub> , R <sub>ADJ</sub> is kΩ	0.6		1.4	V
	I/Q gain mismatch	0 to 11 MHz band		0.1	0.5	dB
	I/Q phase imbalance	0 to 11 MHz band		0.9	3	°
	I/Q differential DC offset	After calibration. Min Gain			10	mV
		Before calibration			50	mV
	DC offset calibration time	With 40 MHz reference. See calibration instructions		32		µs

**RECEIVER CHARACTERISTICS (continued)**

$T_A = 25^\circ\text{C}$  and  $V_{CC} = 3.3\text{ V}$  (unless otherwise noted)

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
	LPF attenuation	25 MHz	20	25		dB
		10.55 MHz		1		dB

**TRANSMITTER CHARACTERISTICS**

TR = High, 2dB base band filter loss in RX band, MIN, TYP, and MAX rating are at  $25^\circ\text{C}$  and  $V_{CC} = 3.3\text{ V}$  (unless otherwise noted)

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
$Z_{ID}$	Differential input impedance	I, Q inputs. (0 – 11MHz)	10			$k\Omega$
$V_{IC}$	Common-mode input voltage	Effected by V+. TRF2432	1.1		2.1	V
$V_I$	Input voltage	I, Q inputs, differential.		0.3		V <sub>pd</sub>
$f_{IF}$	IF input frequency			374		MHz
	Voltage gain	TX Gain Control Word} = {11111} <sup>(1)</sup> , 200- $\Omega$ differential output	3	5		dB
	Gain control range			31		dB
	Gain step size	Per bit		1		dB
	Sideband suppression	0 to 11 MHz band	25	30		dB
	IFLO leakage	Max. gain settings. TX IQ DC offset < 1 mV		-40	-35	dBm
	Output 1dB compression	Maximum gain setting	2	4		dBm
	Output noise	Maximum Gain. Decreasing 1dB per dB attenuation until 15 dB		-137	-131	dBm/Hz
		16 to 31dB down from max gain.		-145	-144	dBm/Hz

(1) Gain is referenced to the amplitude of either the I or Q signal, when they are in quadrature. i.e. For  $I = 0.5 \times \sin(\omega t)$  and  $Q = 0.5 \times \cos(\omega t)$  input in differential volts. The output at a gain of 0dB would ideally be a single tone at 0.5V differential across the 200- $\Omega$  outputs.

**COMMON ELECTRICAL CHARACTERISTICS**

MIN, TYP, and MAX ratings are at  $25^\circ\text{C}$  and  $V_{CC} = 3.3\text{ V}$  (unless otherwise noted)

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
	IF IO differential impedance			200		$\Omega$

**SYNTHESIZER CHARACTERISTICS****RF SYNTHESIZER CHARACTERISTICS**

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
	Frequency range		2536		3150	MHz
	Tuning step			250		kHz
	Settling time	$\pm 10\text{kHz}$ of final frequency. From Standby to Idle measured from enable		60		$\mu\text{s}$
	Phase noise (VCO)	4.5 MHz offset		-130		dBc/Hz
		20 MHz offset		-143		dBc/Hz
	Integrated phase error	10 kHz to 10 MHz		0.6		$^\circ\text{rms}$
	Spurious suppression	$0.25 < \Delta f < 3\text{ MHz}$ offset		$-45-7\Delta f$		dBc
		$> 3\text{ MHz}$ offset		-70		dBc
	Power output	Into 100 $\Omega$ differential. With matching	-2	0		dBm

## INTEGER MODE IF SYNTHESIZER CHARACTERISTICS

 $f_{REF} = 44 \text{ MHz}$ 

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
	Frequency	With 44 MHz crystal		374		MHz
	Settling time	$\pm 10\text{kHz}$ of final frequency. From Standby to Idle measured from enable		60		$\mu\text{s}$
	Integrated phase error	10 kHz to 10 MHz		0.2		$^{\circ}\text{rms}$
	Spurious suppression	> 3 MHz offset		-70		dBc

## FRACTIONAL MODE IF SYNTHESIZER CHARACTERISTICS

 $f_{REF} = 40 \text{ MHz}$ 

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
	Frequency	With 44 MHz crystal		374		MHz
	Settling time	$\pm 10\text{kHz}$ of final frequency. From Standby to Idle measured from enable		60		$\mu\text{s}$
	Integrated phase error	10 kHz to 10 MHz		0.1		$^{\circ}\text{rms}$
	Spurious suppression	$0.25 < \Delta f < 3 \text{ MHz}$ offset		$-45-7\Delta f$		dBc
		> 3 MHz offset		-70		dBc

## PLL REFERENCE/CLOCK OUTPUT CHARACTERISTICS

The TRF2432 synthesizers operate from a single 40 or 44 MHz reference. The TRF2432 can generate its own PLL reference using an internal oscillator or it may also be driven from an external reference. The TRF2432 provides a user selectable, buffered clock output for base-band ASICs.

## PLL REFERENCE OSCILLATOR SPECIFICATIONS

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
$f_{REF}$	Reference frequency			40 or 44		MHz
	Start-up time	From power on. Depends on Crystal characteristics		0.5		ms
	Degradation to Crystal Reference Accuracy	From crystal series resonance.		0.25		PPM
	Jitter			5	10	ps
	External XO drive	Square-wave, must be AC Coupled	0.8	1	2	$V_{pp}$
	Equivalent input load	Single ended		50  10		$\Omega  \text{pF}$

## RECOMMENDED CRYSTAL SPECIFICATIONS

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
f	Frequency	Series resonant, fundamental or 3rd overtone		40 or 44		MHz
ESR	Effective series resistance				100	$\Omega$
C	Shunt capacitance				20	pF
	Maximum power handling				50	$\mu\text{W}$
	Frequency accuracy	Over Temperature and Process			20	PPM

### CLOCK OUTPUT CHARACTERISTICS

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
f <sub>CLK</sub>	Clock output frequency	REFDIV = 1		f <sub>REF</sub> /2		MHz
		REFDIV = 0		f <sub>REF</sub>		MHz
	Output voltage swing	Differential	0.4	1		V <sub>ppd</sub>
DC	Duty cycle			50%		
t <sub>r</sub>	Rise time				3	ns
t <sub>f</sub>	Fall time				3	ns
C <sub>L</sub>	Capacitance load	Per side			8	pF

### DIGITAL INTERFACE CHARACTERISTICS

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
V <sub>IH</sub>	High-level input voltage		1.7			V
V <sub>IL</sub>	Low-level input voltage				0.5	V
V <sub>OH</sub>	High-level output voltage	100-μA load current	2			V
V <sub>OL</sub>	Low-level output voltage	-100-μA load current			0.2	V

### SERIAL INTERFACE TIMING REQUIREMENTS

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
	Power Enable to Serial port on	From Sleep mode to standby mode. PE High transition.	0.5			μs
	Enable clock	Time to activate the serial port to receive clocked and data.	10			ns
	Hold time, data to clock		10			ns
	Setup time, data to clock		10			ns
	Clock low duration		10			ns
	Clock high duration		10			ns
	Setup time, clock to enable		10			ns
	Enable time	Should be held high when not programming	10			ns

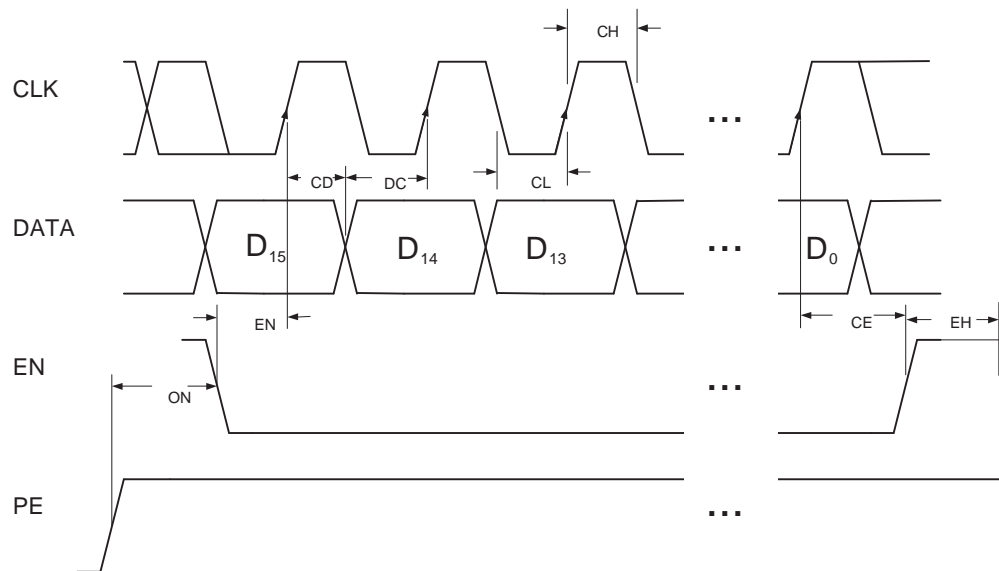


Figure 1. Serial Interface Timing Diagram



## SERIAL REGISTERS

Data is written to the registers per the following format:

**Table 2. Serial Interface Data Format**

REGISTERS									ADDRESS							
(MSB) 1st BIT IN									LAST BIT IN (LSB)							
#	D15	D14	D13	D12	D11	D10	D9	D8	D7	D6	D5	D4	D3	D2	D1	D0
1	GCX	TX_HP	REF_S	FN_IF	X	A/B	PS1	PS0	1	1	0	1	1	0	1	0
2	CP	S_INV	REF_M	GC4	GC3	GC2	GC1	GC0	1	1	0	1	1	1	1	1
3	P	MR6	MR5	MR4	MR3	MR2	MR1	MR0	1	1	0	1	1	1	0	1
4	X	FI6	FI5	FI4	FI3	FI2	FI1	FI0	1	1	0	1	1	0	0	0
5	X	MI6	MI5	MI4	MI3	MI2	MI1	MI0	1	1	0	1	1	0	0	1
6	DI4	DI3	DI2	DI1	DI0	SI2	SI1	SI0	1	1	0	1	1	0	1	1
7	XO_LP	FR6	FR5	FR4	FR3	FR2	FR1	FR0	1	1	0	1	1	1	0	0
8	DR4	DR3	DR2	DR1	DR0	SR2	SR1	SR0	1	1	0	1	1	1	1	0

**Table 3. Serial Register Definitions**

NAME	SYMBOL	# OF BITS	DEFAULTS <sup>(1)</sup>	DESCRIPTION
Power mode	PS	2	0	Determines mode of operation: Standby, Idle, or Active. (see Table 17)
Band A or B select	A/B	1	0	Selects TX and RX band. 1 = A band and 0 = B Band
TX gain control	GC	5	[x,x,x,x,x]	Controls gain setting of TX if CGX=0 (see below). {11111} is max gain and {00000} is minimum gain.
Spectral inversion	S_INV	1	1	Sets both the TX I/Q modulator and RX I/Q demodulator for spectral inversion. S_INV = 1 for spectral inversion. S_INV = 0 for no inversion.
Crystal pre-scalar	P	1	1	Sets the crystal or reference pre-scalar divider.
RF PLL frequency	DR	5	[0,1,0,1,0] = 10	Registers used to program the RF synthesizer operation frequency.
	SR	3	[0,0,0] = 0	
	FR	7	[0,1,1,0,0,0,0]=48	
	MR	7	[1,0,0,1,1,1,1]=79	
IF PLL frequency	DI	5	X	Registers used to program the IF synthesizer operation frequency. These registers are only effective, when the IF synthesizer is in fractional-N mode (i.e. FN_IF=1)
	SI	3	X	
	FI	7	X	
	MI	7	X	
TX gain control MUX	GCX	1	1	GCX=0 switches the Tx gain control to the serial port. GCX=1 switches the Tx gain control to the parallel input pins.
Fractional N IF synthesizer	FN_IF	1	0	FN_IF =1 enables the fractional N IF synthesizer FN = 0 sets the IF synthesizer to a fixed frequency
REF_S	REF_S	1	0	Always set REF_S = 0
REF_M	REF_M	1	0	Always set REF_M = 0
Charge Pump Current Setting	CP	1	0	CP = 1 puts charge pump for reference and fixed synthesizers into continuous current mode. CP = 0 puts synthesizers into current saving mode.
XO low power mode	XO_LP	1	1	XO_LP =1 puts crystal oscillator in low power mode. XO_LP = 0 puts the crystal oscillator full-power mode for better noise performance, and start-up time.

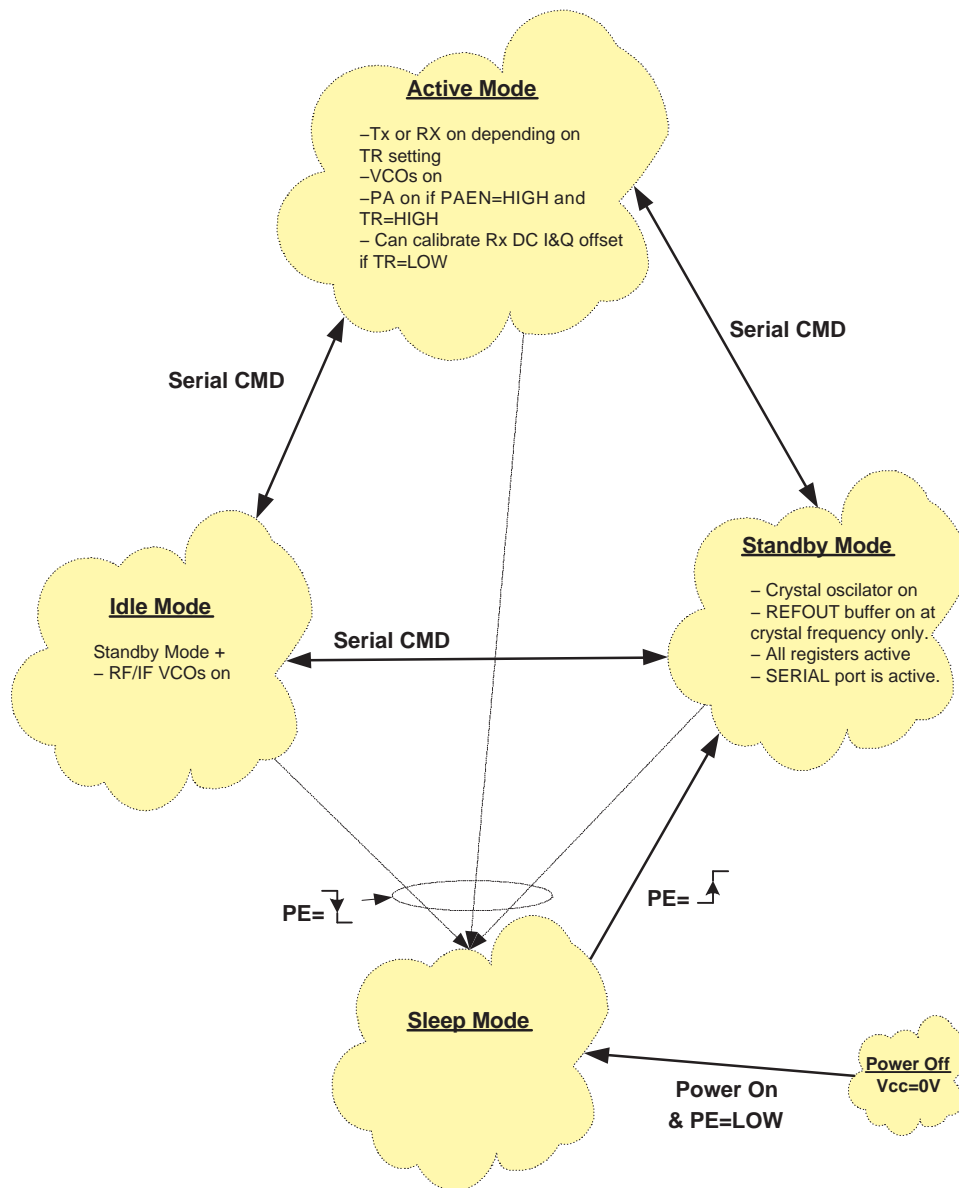
(1) Default values are the initial values after power up or after PE goes HIGH. "x" indicates undefined.

**Table 3. Serial Register Definitions (continued)**

NAME	SYMBOL	# OF BITS	DEFAULTS <sup>(1)</sup>	DESCRIPTION
Fractional N IF synthesizer	FN_IF	1	0	FN_IF = 1 enables the fractional N IF synthesizer when in idle or active mode. FN = 0 sets the IF synthesizer to a fixed frequency (374 MHz with 44 MHz crystal) for low power consumption.
TX output buffer high power	TX_HP	1	0	TX_HP = 1 puts IF amplifier in high linearity mode. TX_HP = 0 puts the IF amplifier into normal linearity mode to save current. This does not change linearity of the RFFE.

**MODES OF OPERATION**

**Power Modes**



**Figure 2. Power Modes**

## MODES OF OPERATION (continued)

Table 4. Power Mode Descriptions

MODE	PS1	PS0	RFFE	TX	RX	IF PLL	RF PLL	CLK OUT	XO	SERIAL	COMMENTS
Active	1	1	X	X	X	X	X	X	X	X	TR_SEL controls Transmit/Receive mode
Idle	0	1				X	X	X	X	X	Register settings retained
Standby		0						X	X	X	Register settings retained
Sleep											Settings not required

### Input/Output Modes

The TRF2432 is designed to control power and band status for a TI RFFE. The TRF2432 is designed to drive external P-MOSFETs to power up and down the appropriate sections of the RFFE. Table 4 lists the various modes of the TRF2432 and the input parameters required to enter each mode. The corresponding outputs to the RFFE are also described. Figure 4 illustrates the power control interface and recommended P-MOSFET circuit.

Table 5. Inputs/Outputs and Operational States

OPERATION STATE	INPUT PARAMETERS							OUTPUT DRIVERS				INTERNAL FUNCTIONS				
	PINS				REGISTERS			PAPDA	PAPDB	RFPD	ABSEL	TX	RX	SYNTHESIZERS	CRYSTAL OSC. AND DRIVER	SERIAL BUS
	PE	TR	PAEN	CALEN	PS1	PS0	A/B									
Sleep mode	Low	X	X	X	X	X	X	High	High	High	Low	Off	Off	Off	Off	Off
Standby mode	High	X	X	X	X	0	X	High	High	High	Low	Off	Off	Off	On	On
Idle mode	High	X	X	X	0	1	X	High	High	High	Low	Off	Off	Enabled	On	On
Active mode (PA disabled)	High	X	Low	X	1	1	X	High	High	Low	=(A/B)	Enabled	Enabled	Enabled	On	On
Active mode (RX A band)	High	Low	Low	X	1	1	1	High	High	Low	High	Off	On	Enabled	On	On
Active mode (TX A band)	High	High	High	X	1	1	1	Low	High	Low	High	On	Off	Enabled	On	On
Active mode (RX B band)	High	Low	Low	X	1	1	0	High	High	Low	Low	Off	On	Enabled	On	On
Active mode (TX B band)	High	High	High	X	1	1	0	High	Low	Low	Low	On	Off	Enabled	On	On
Active mode (RX-Cal.)	High	Low	Low	Rising Edge	1	1	X	High	High	High <sup>(1)</sup>	=(A/B)	Off	On	Enabled	On	On

(1) Held in open state until calibration is complete or disabled (CAL\_EN = High -> Low).

### SYNTHESIZER PROGRAMMING

The RF synthesizer frequency is programmed with four bytes: DR, SR, FR and MR and the crystal pre-scalar: P. See digital interface characteristics for programming instructions). The RF PLL locking frequency is calculated as follows:

$$f_{\text{RFLO}} = \frac{f_{\text{RCF}}}{(P + 1)} \times \left[ 8 \times (DR + 3) - SR - \frac{FR}{(MR + 1)} \right] \quad (1)$$

$f_{\text{REF}}$  is the crystal reference frequency. On power-up the default register values (P=1, DR=10, SR=0, FR=48 and MR=79) with a 40-MHz crystal will attempt to lock the RFLO to 2068 MHz. The valid register ranges are listed below.

Table 6. Valid RF Register Ranges

REGISTER	MIN	MAX
DR	7	31
SR	0	7

**Table 6. Valid RF Register Ranges (continued)**

REGISTER	MIN	MAX
FR	0	MR
MR	32	127

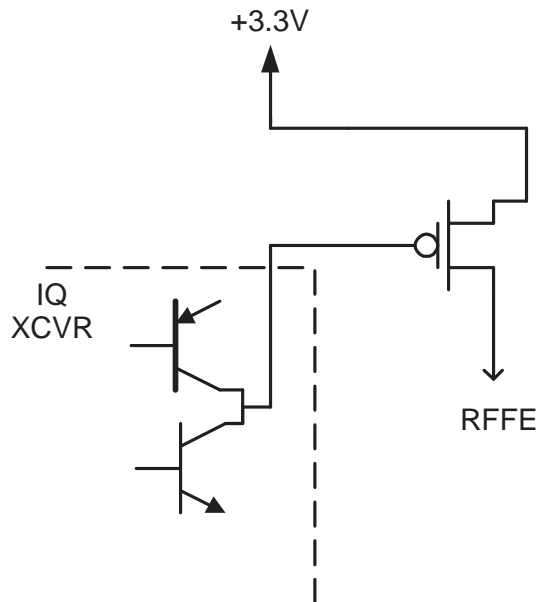
The IF frequency synthesizer defaults to integer mode (FN\_IF =0) to operate from a 44 MHz reference and is preset for 374 MHz IF. When using a 40 MHz reference, the synthesizer must be set to fractional mode (FN\_IF =1) and programmed. The synthesizer is programmed with four bytes DI, SI, FI and MI. The register programming values for the IF synthesizer when using a 40 MHz reference are listed in Table 21.

**Table 7. IF Register Values for 40-MHz Reference**

REGISTER	VALUE
DI	16
SI	2
FI	32
MI	79

**RFFE POWER CONTROL INTERFACE**

The TRF2432 will control the RFFE power for all radio operational modes through three external P-MOSFETs. The suggested circuit is illustrated in Figure 4.



**Figure 3.**

**IQ DC Calibration**

The TRF2432 receiver has an IQ DC offset calibration function. This operation can be performed in receiver active mode only. The calibration process is entered by a rising edge on CALEN, which remains high as long as the calibration is required. The calibration procedure is as follows:

1. Set to RX active mode
2. Wait for RF and IF Synthesizers to lock: STATUS=HIGH
3. Set Rx AGC to min gain
4. Set CALEN=HIGH to enter calibration mode:
  - a. IQ Transceiver turns off RFFE
  - b. Internal calibration process runs

- c. The Status bit is low during calibration procedure and returns high once the calibration is complete
- 5. Hold CALEN HIGH to maintain calibration
- 6. Return to RX active Mode

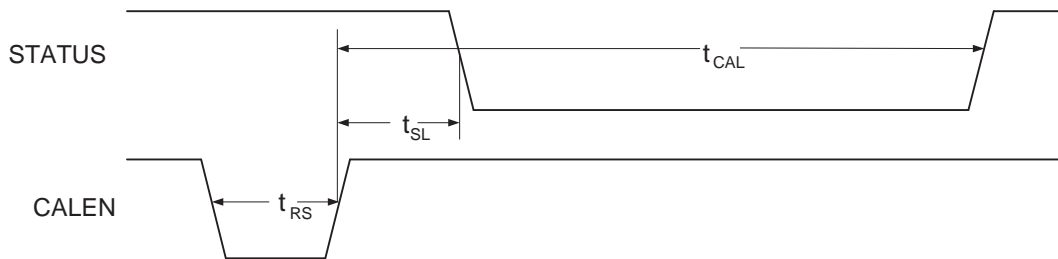
Notes on Calibration:

- 1. Calibration is retained as long as CALEN=HIGH and the RF2432 is **not** put into Sleep Mode.
- 2. To Reset calibration, set CALEN=LOW.
- 3. If CALEN is held LOW then calibration circuit is completely disabled, and does not contribute to any DC offset.

**IQ DC Calibration Timing**

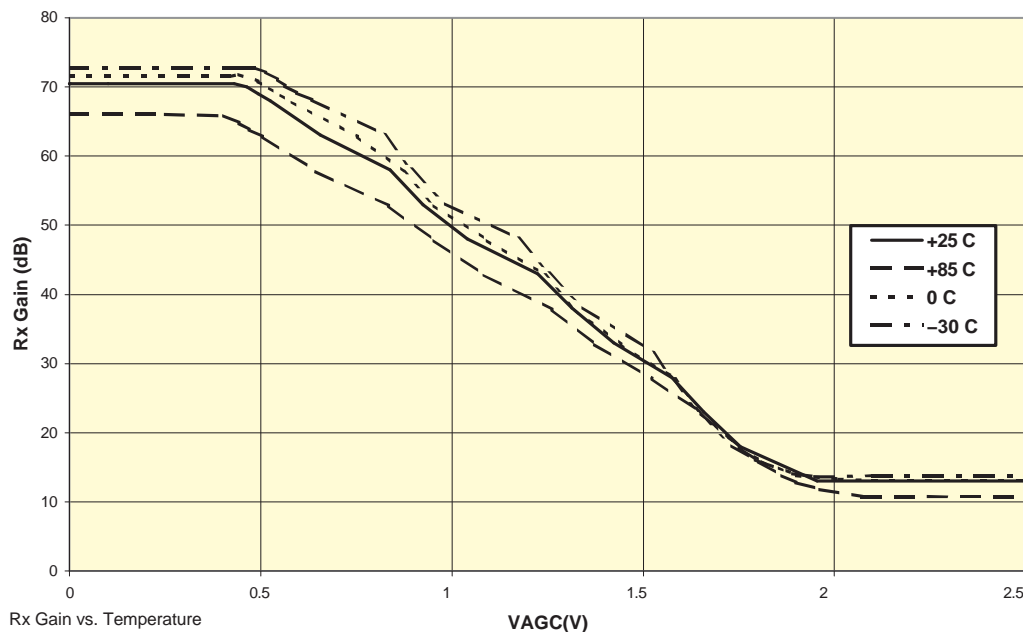
**Table 8. Calibration Timing Requirements**

PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
Calibration reset		4			µs
Status low				1	µs
Calibration time	1 tick = 44/f <sub>REF</sub> (e.g., f <sub>REF</sub> = 44 MHz, tick = 1 µs)			68	tick



**Figure 4. Calibration Timing**

**TYPICAL CHARACTERISTICS**



**Figure 5. RX Gain Control vs Temperature**

TYPICAL CHARACTERISTICS (continued)

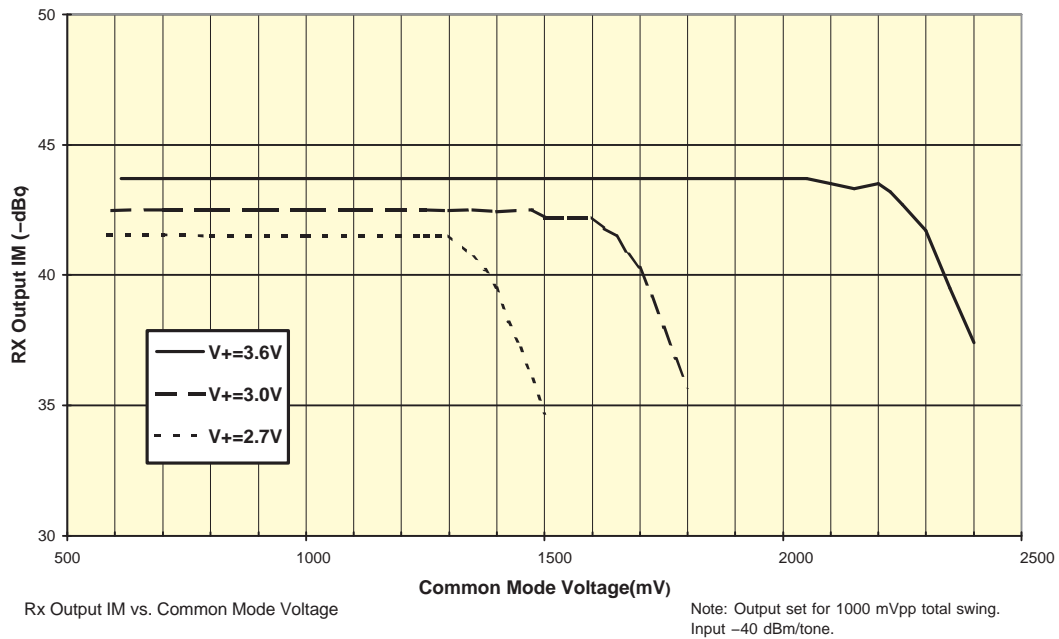


Figure 6. RX Intermod Level vs Common-Mode Voltage

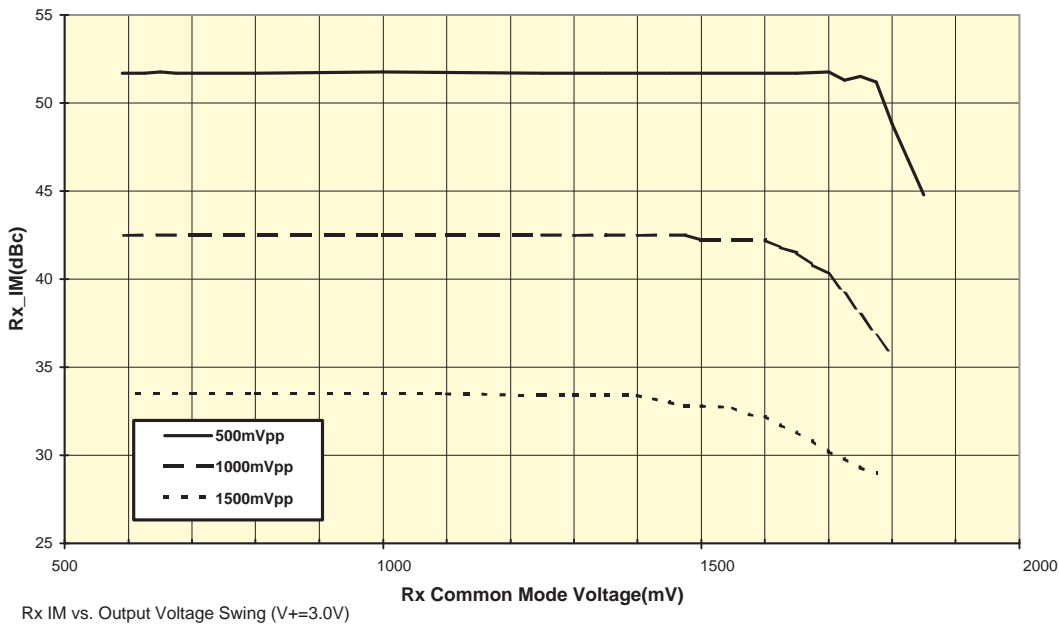
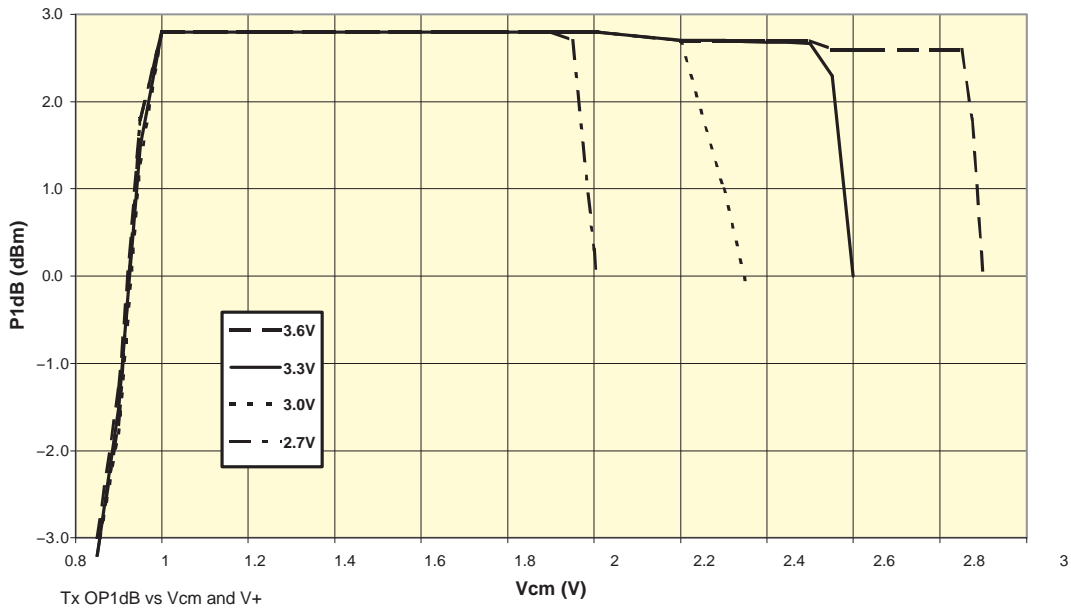


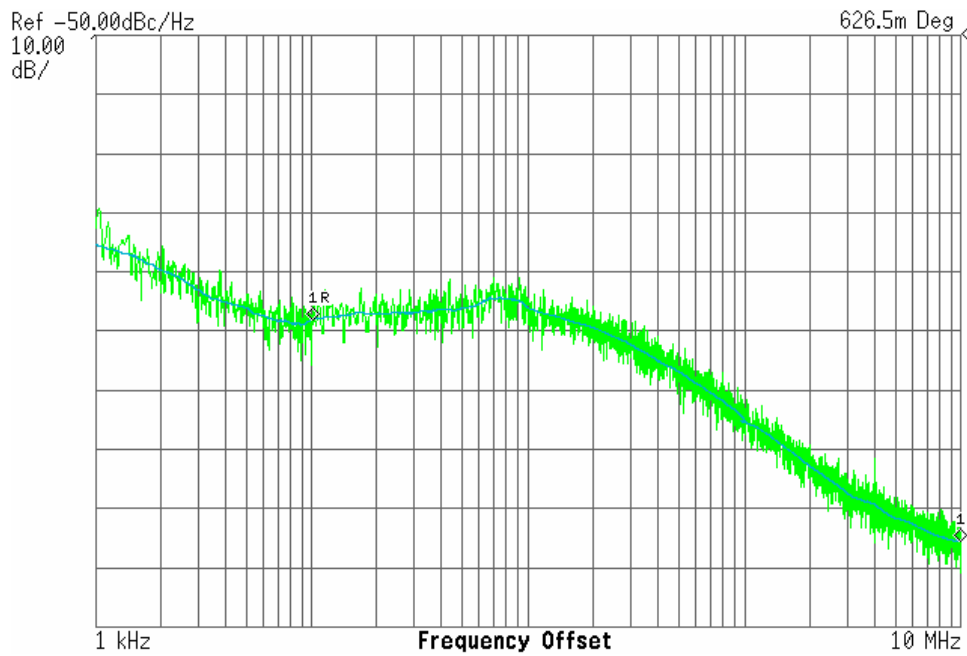
Figure 7. RX Intermod. Level vs Output Voltage Swing

**TYPICAL CHARACTERISTICS (continued)**



**Figure 8. TX OP1dB vs Common-Mode Input Voltage**

**RF SYNTHESIZER PERFORMANCE**



**Figure 9. RFLO Phase Noise**

RF SYNTHESIZER PERFORMANCE (continued)

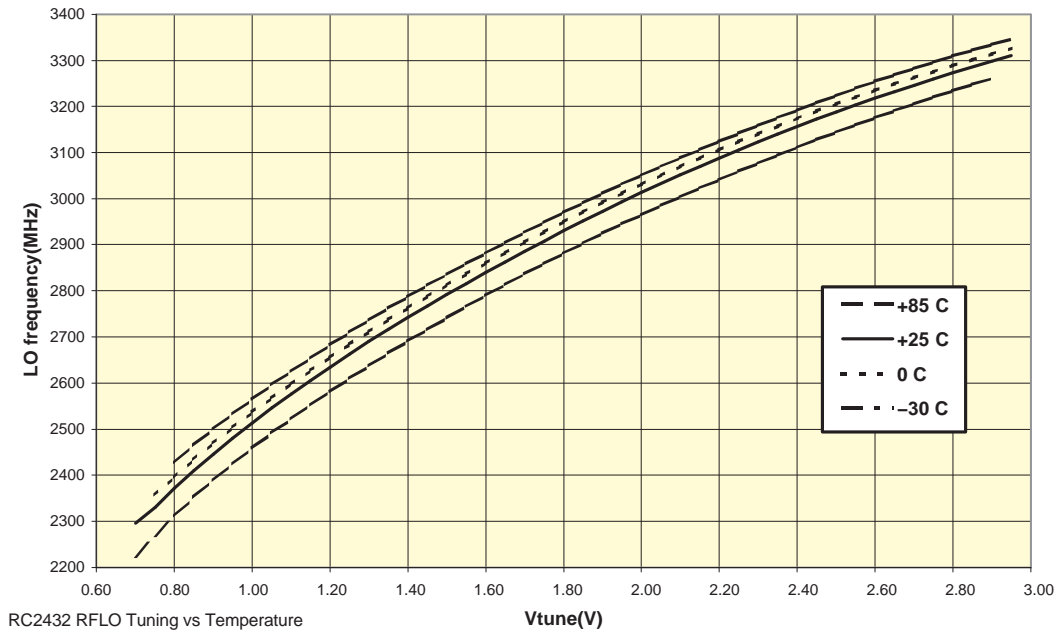


Figure 10. RF VCO Tuning Curves vs Voltages

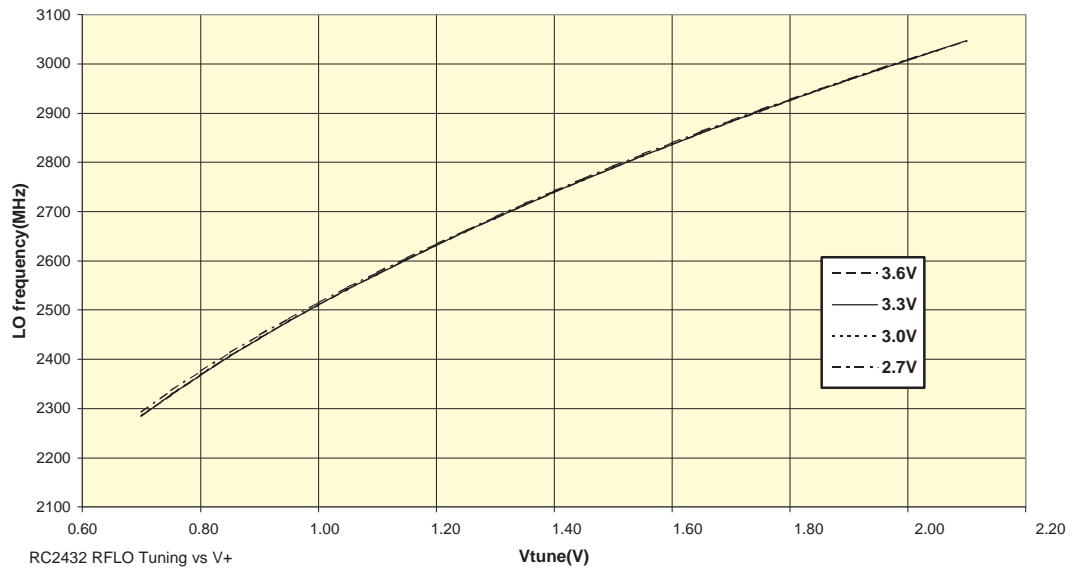
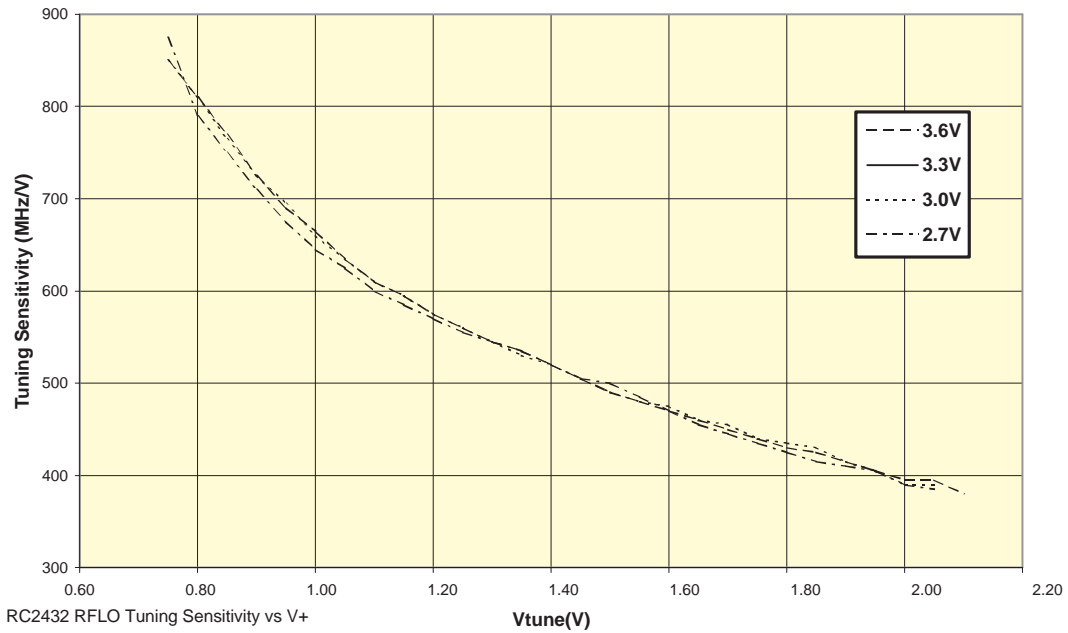


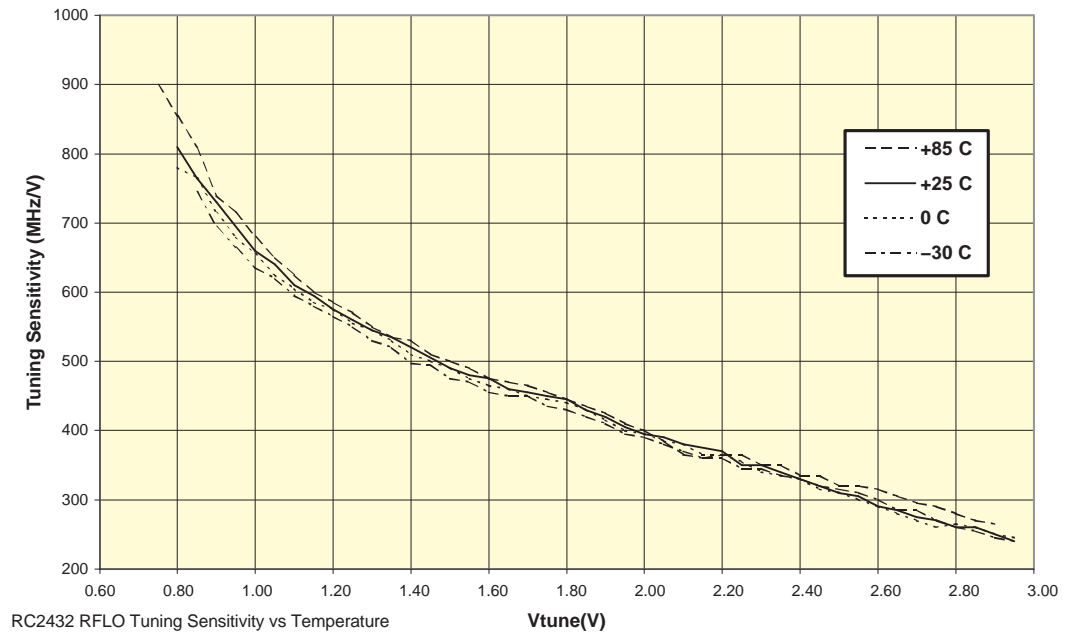
Figure 11. RF VCO Tuning Curves vs Temperature



**RF SYNTHESIZER PERFORMANCE (continued)**



**Figure 12. RF VCO Tuning Sensitivity vs V<sub>CC</sub>**



**Figure 13. RFLO Tuning Sensitivity vs Temperature**

IF SYNTHESIZER PERFORMANCE

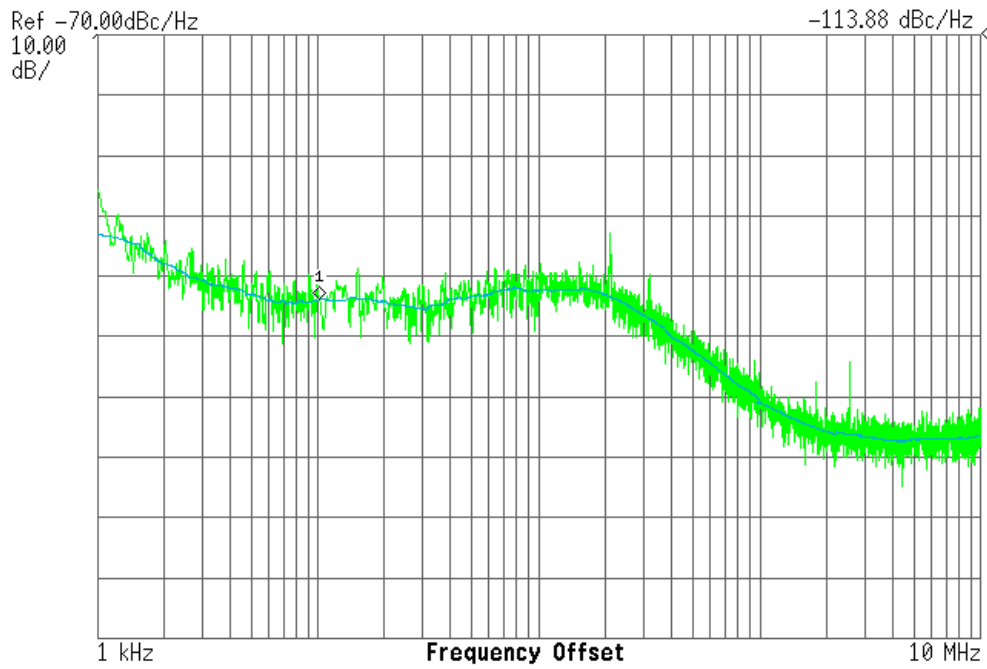


Figure 14. IF Synthesizer Phase Noise

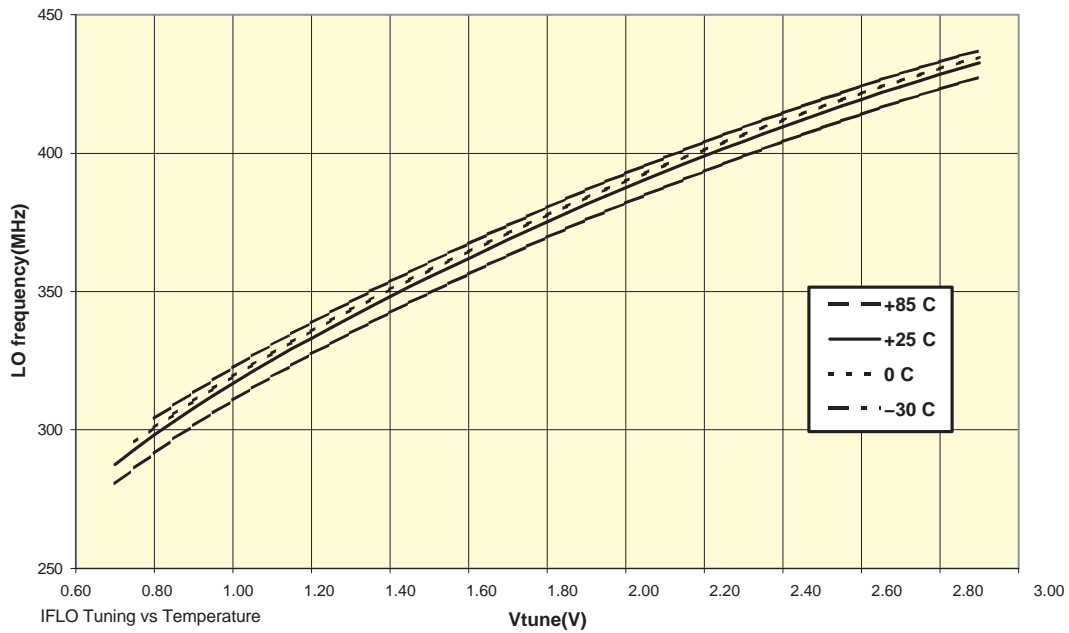
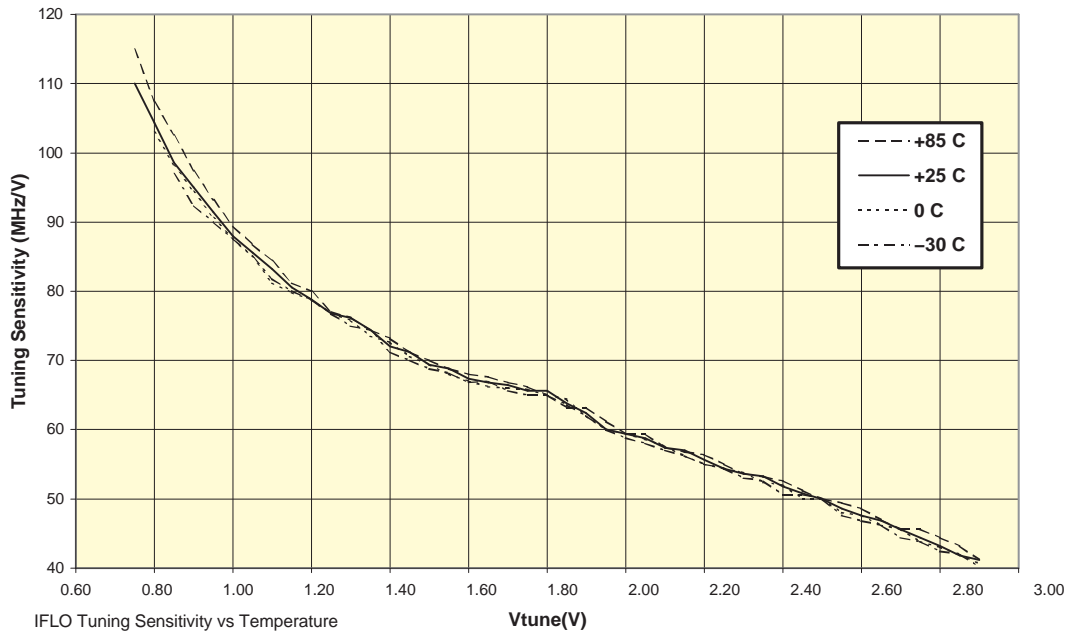
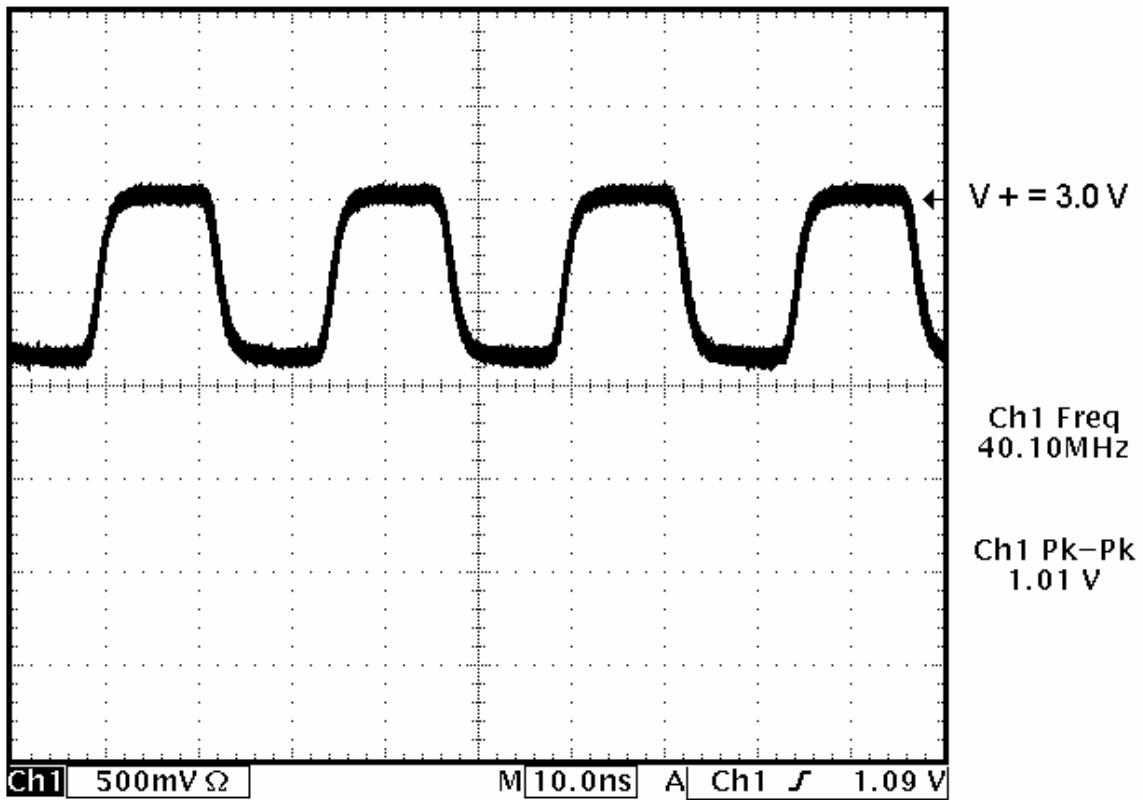


Figure 15. IFLO Tuning Curves vs Temperature

**IF SYNTHESIZER PERFORMANCE (continued)**



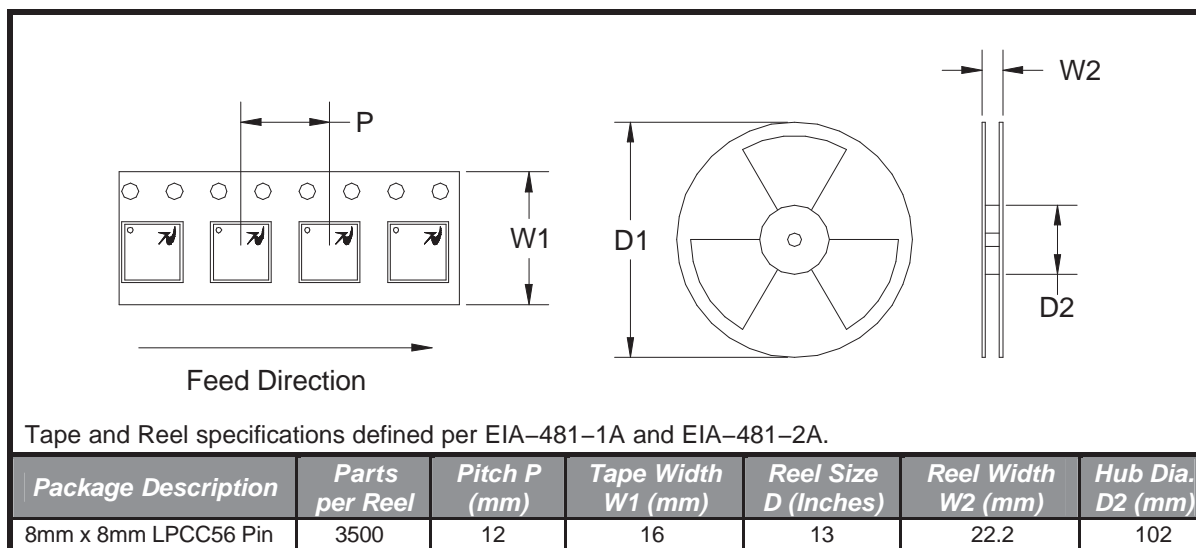
**Figure 16. IFLO Tuning Sensitivity vs Temperature**



**Figure 17. Reference Clock Differential Output**



**APPLICATION INFORMATION (continued)**



**Figure 19. Tape and Reel Specifications**

**PACKAGING INFORMATION**

Orderable Device	Status <sup>(1)</sup>	Package Type	Package Drawing	Pins	Package Qty	Eco Plan <sup>(2)</sup>	Lead/Ball Finish	MSL Peak Temp <sup>(3)</sup>
TRF2432IRTQR	ACTIVE	QFN	RTQ	56	2500	Green (RoHS & no Sb/Br)	CU SN	Level-3-260C-168 HR
TRF2432IRTQRG3	ACTIVE	QFN	RTQ	56	2500	Green (RoHS & no Sb/Br)	CU SN	Level-3-260C-168 HR
TRF2432IRTQT	ACTIVE	QFN	RTQ	56	250	Green (RoHS & no Sb/Br)	CU SN	Level-3-260C-168 HR
TRF2432IRTQTG3	ACTIVE	QFN	RTQ	56	250	Green (RoHS & no Sb/Br)	CU SN	Level-3-260C-168 HR

<sup>(1)</sup> The marketing status values are defined as follows:

**ACTIVE:** Product device recommended for new designs.

**LIFEBUY:** TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

**NRND:** Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

**PREVIEW:** Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

<sup>(2)</sup> Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check <http://www.ti.com/productcontent> for the latest availability information and additional product content details.

**TBD:** The Pb-Free/Green conversion plan has not been defined.

**Pb-Free (RoHS):** TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

**Pb-Free (RoHS Exempt):** This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

**Green (RoHS & no Sb/Br):** TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

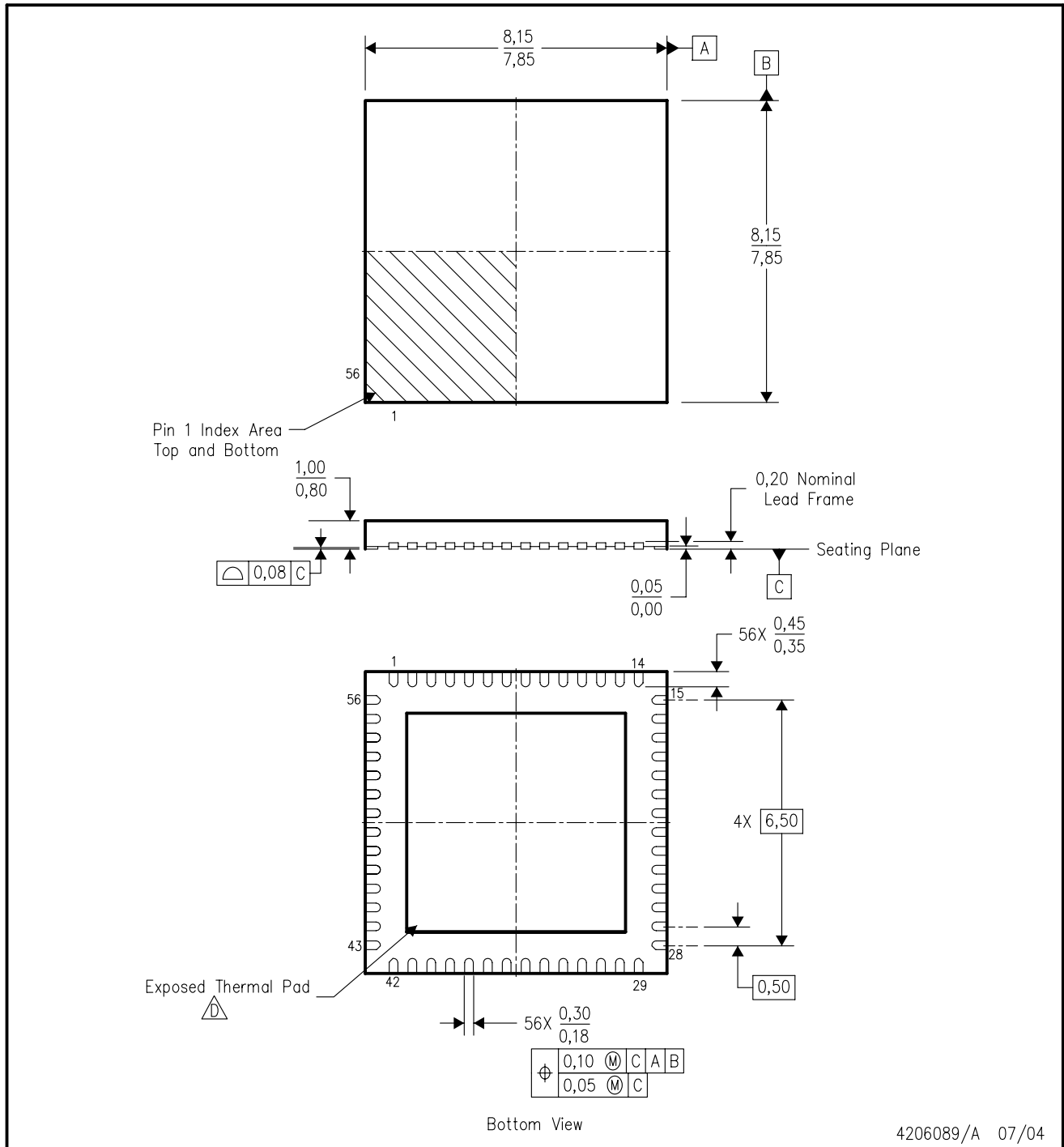
<sup>(3)</sup> MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

**Important Information and Disclaimer:**The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

RTQ (S-PQFP-N56)

PLASTIC QUAD FLATPACK



- NOTES:
- All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5-1994.
  - This drawing is subject to change without notice.
  - QFN (Quad Flatpack No-Lead) Package configuration.
  - The package thermal pad must be soldered to the board for thermal and mechanical performance. See the Product Data Sheet for details regarding the exposed thermal pad dimensions.
  - Package complies to JEDEC MO-220.

## IMPORTANT NOTICE

Texas Instruments Incorporated and its subsidiaries (TI) reserve the right to make corrections, modifications, enhancements, improvements, and other changes to its products and services at any time and to discontinue any product or service without notice. Customers should obtain the latest relevant information before placing orders and should verify that such information is current and complete. All products are sold subject to TI's terms and conditions of sale supplied at the time of order acknowledgment.

TI warrants performance of its hardware products to the specifications applicable at the time of sale in accordance with TI's standard warranty. Testing and other quality control techniques are used to the extent TI deems necessary to support this warranty. Except where mandated by government requirements, testing of all parameters of each product is not necessarily performed.

TI assumes no liability for applications assistance or customer product design. Customers are responsible for their products and applications using TI components. To minimize the risks associated with customer products and applications, customers should provide adequate design and operating safeguards.

TI does not warrant or represent that any license, either express or implied, is granted under any TI patent right, copyright, mask work right, or other TI intellectual property right relating to any combination, machine, or process in which TI products or services are used. Information published by TI regarding third-party products or services does not constitute a license from TI to use such products or services or a warranty or endorsement thereof. Use of such information may require a license from a third party under the patents or other intellectual property of the third party, or a license from TI under the patents or other intellectual property of TI.

Reproduction of information in TI data books or data sheets is permissible only if reproduction is without alteration and is accompanied by all associated warranties, conditions, limitations, and notices. Reproduction of this information with alteration is an unfair and deceptive business practice. TI is not responsible or liable for such altered documentation.

Resale of TI products or services with statements different from or beyond the parameters stated by TI for that product or service voids all express and any implied warranties for the associated TI product or service and is an unfair and deceptive business practice. TI is not responsible or liable for any such statements.

Following are URLs where you can obtain information on other Texas Instruments products and application solutions:

### Products

Amplifiers	<a href="http://amplifier.ti.com">amplifier.ti.com</a>
Data Converters	<a href="http://dataconverter.ti.com">dataconverter.ti.com</a>
DSP	<a href="http://dsp.ti.com">dsp.ti.com</a>
Interface	<a href="http://interface.ti.com">interface.ti.com</a>
Logic	<a href="http://logic.ti.com">logic.ti.com</a>
Power Mgmt	<a href="http://power.ti.com">power.ti.com</a>
Microcontrollers	<a href="http://microcontroller.ti.com">microcontroller.ti.com</a>
Low Power Wireless	<a href="http://www.ti.com/lpw">www.ti.com/lpw</a>

### Applications

Audio	<a href="http://www.ti.com/audio">www.ti.com/audio</a>
Automotive	<a href="http://www.ti.com/automotive">www.ti.com/automotive</a>
Broadband	<a href="http://www.ti.com/broadband">www.ti.com/broadband</a>
Digital Control	<a href="http://www.ti.com/digitalcontrol">www.ti.com/digitalcontrol</a>
Military	<a href="http://www.ti.com/military">www.ti.com/military</a>
Optical Networking	<a href="http://www.ti.com/opticalnetwork">www.ti.com/opticalnetwork</a>
Security	<a href="http://www.ti.com/security">www.ti.com/security</a>
Telephony	<a href="http://www.ti.com/telephony">www.ti.com/telephony</a>
Video & Imaging	<a href="http://www.ti.com/video">www.ti.com/video</a>
Wireless	<a href="http://www.ti.com/wireless">www.ti.com/wireless</a>

Mailing Address: Texas Instruments  
Post Office Box 655303 Dallas, Texas 75265